# MSKSEMI 美森科













**ESD** 

115

TSS

MOV

GDT

PLED

### **SMAZXX-MS**

**Product specification** 





## SURFACE MOUNT SILICON ZENER DIODES

**VZ: 5.1 - 39 Volts** 

PD: 1 Watt

#### **FEATURES**

Complete Voltage Range 5.1 to 39 Volts

High Surge Capability

Ideally Suited for Automatic Assembly

Standard VZ Tolerance is ± 5%

Pb / RoHS Free

#### **ECHANICAL DATA**

Case : SMA Molded plastic

Epoxy : UL94V-O rate flame retardant

Polarity : Color band denotes cathode end

Mounting position : Any

• Weight: 0.060 gram (Approximately)

#### **Reference News**

PACKAGE OUTLINE	PIN CONFIGURATION	Marking Information
SMA(DO-214AC)		Notes: SMAZ5V1-MS=Z5V1 SMAZ5V6-MS=Z5V6 SMAZ6V2-MS=Z6V2 And so on

#### **MAXIMUM RATINGS**

Rating at 25 °C ambient temperature unless otherwise specified

Rating	Symbol	Value	Unit
DC Power Dissipation at Ta = 50 °C (Note1)	P <sub>D</sub>	1.0	W
Maximum Forward Voltage at I <sub>F</sub> = 200 mA	V <sub>F</sub>	1.2	V
Temperature Resistance Junction to Ambient (Note 1)	R <sub>0JA</sub>	125	°C
Junction and Storage Temperature Range	T <sub>STG</sub>	- 65 to + 150	°C



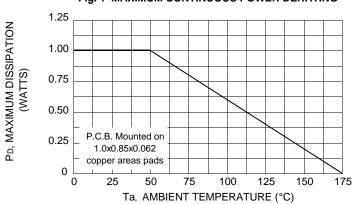


Fig. 1 MAXIMUM CONTINUOUS POWER DERATING

#### **ELECTRICAL CHARACTERISTICS**

Rating at25 °C ambient temperature unless otherwise specified

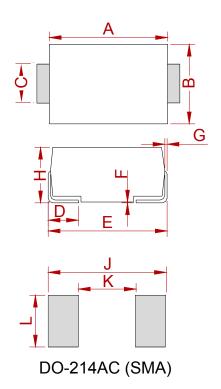
Туре	Mak	Zener Voltage <sup>(2)</sup> V <sub>Z</sub> @ I <sub>ZT</sub>			Maximum Zener Impedance					Maximum Reverse Leakage Current, I <sub>R</sub>		Maximum DC Zener	
Number	ing	Nom	Min	Max	I <sub>ZT</sub>	Z <sub>ZT</sub> @	I <sub>ZT</sub>	Z <sub>Zk</sub> @	Izk	I <sub>zk</sub>	I <sub>R</sub> (	@ V <sub>R</sub>	Current <sup>(1)</sup>
		(V)	(V)	(V)	(mA)	(Ω)		(Ω)		(mA)	(μΑ)	(V)	I <sub>ZM</sub> (mA)
SMAZ5V1-MS	Z5V1	5.1	4.84	5.40	100	5.0		500		1.0	2.5	1.0	196
SMAZ5V6-MS	Z5V6	5.6	5.32	5.88	100	2.0		250		2.0	5.0	2.0	179
SMAZ6V2-MS	Z6V2	6.2	5.89	6.51	100	2.0		200		2.0	5.0	3.0	161
SMAZ6V8-MS	Z6V8	6.8	6.46	7.14	100	2.0		200		1.0	5.0	4.0	147
SMAZ7V5-MS	Z7V5	7.5	7.13	7.88	100	2.0		450		1.0	5.0	5.0	133
SMAZ8V2-MS	Z8V2	8.2	7.79	8.61	100	2.0		200		1.0	5.0	6.0	122
SMAZ9V1-MS	Z9V1	9.1	8.65	9.56	50	4.0		200		1.0	5.0	7.0	10
SMAZ10-MS	Z10	10.0	9.50	10.50	50	4.0		200		1.0	1.0	7.6	100
SMAZ12-MS	Z12	12.0	11.40	12.60	50	7.0		150		1.0	1.0	9.1	83
SMAZ15-MS	Z15	15.0	14.25	15.75	50	10		150		1.0	1.0	11.4	67
SMAZ16-MS	Z16	16.0	15.20	16.80	25	15		150		1.0	0.5	12.2	63
SMAZ18-MS	Z18	18.0	17.10	18.90	25	15		150		1.0	0.5	13.7	56
SMAZ20-MS	Z20	20.0	19.00	21.00	25	15		180		1.0	0.5	15.2	50
SMAZ22-MS	<b>Z</b> 22	22.0	20.90	23.10	25	15		180		1.0	0.5	16.7	45
SMAZ24-MS	<b>Z</b> 24	24.0	22.80	25.20	25	15		180		1.0	0.5	18.2	42
SMAZ27-MS	<b>Z</b> 27	27.0	25.65	28.35	25	15		200		1.0	0.5	20.5	37
SMAZ30-MS	Z30	30.0	28.50	31.50	25	15		250		1.0	0.5	22.8	33
SMAZ33-MS	Z33	33.0	31.35	34.65	25	15		300		1.0	0.5	25.1	30
SMAZ36-MS	Z36	36.0	34.20	37.80	10	40		350		1.0	0.5	27.4	28
SMAZ39-MS	Z39	39.0	37.05	40.95	10	40		450		1.0	0.5	29.6	26

#### Notes:

- (1) P.C.B. Mounted on 1.0" x 0.85" x 0.062" copper areas pads.
- (2) Short duration test pulse used to minimize self-heating effect.
- (3) "SMA" will be omitted in marking on the diode.



#### **PACKAGE MECHANICAL DATA**



	Dimensions					
Ref.	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
Α	4.25	4.65	0.167	0.183		
В	2.50	2.90	0.098	0.114		
С	1.35	1.65	0.053	0.065		
D	0.76	1.52	0.030	0.060		
E	4.93	5.28	0.194	0.208		
F	0.051	0.203	0.002	0.008		
G	0.15	0.31	0.006	0.012		
Н	1.98	2.41	0.078	0.095		
J	6.50		0.256			
K		2.30		0.090		
L	1.70		0.067			

#### **REEL SPECIFICATION**

P/N	PKG	QTY
SMAZXX-MS	SMA	2000



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